



N-M10-C

Monocrystalline Wafer

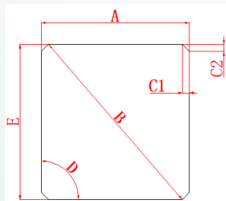
Comprehensive system certification

ISO 9001:2015

ISO 14001:2015

OHSAS 18001:2018

Schematic diagram of wafer size



Size: M10-C

A: $182.2 \pm 0.25\text{mm}$

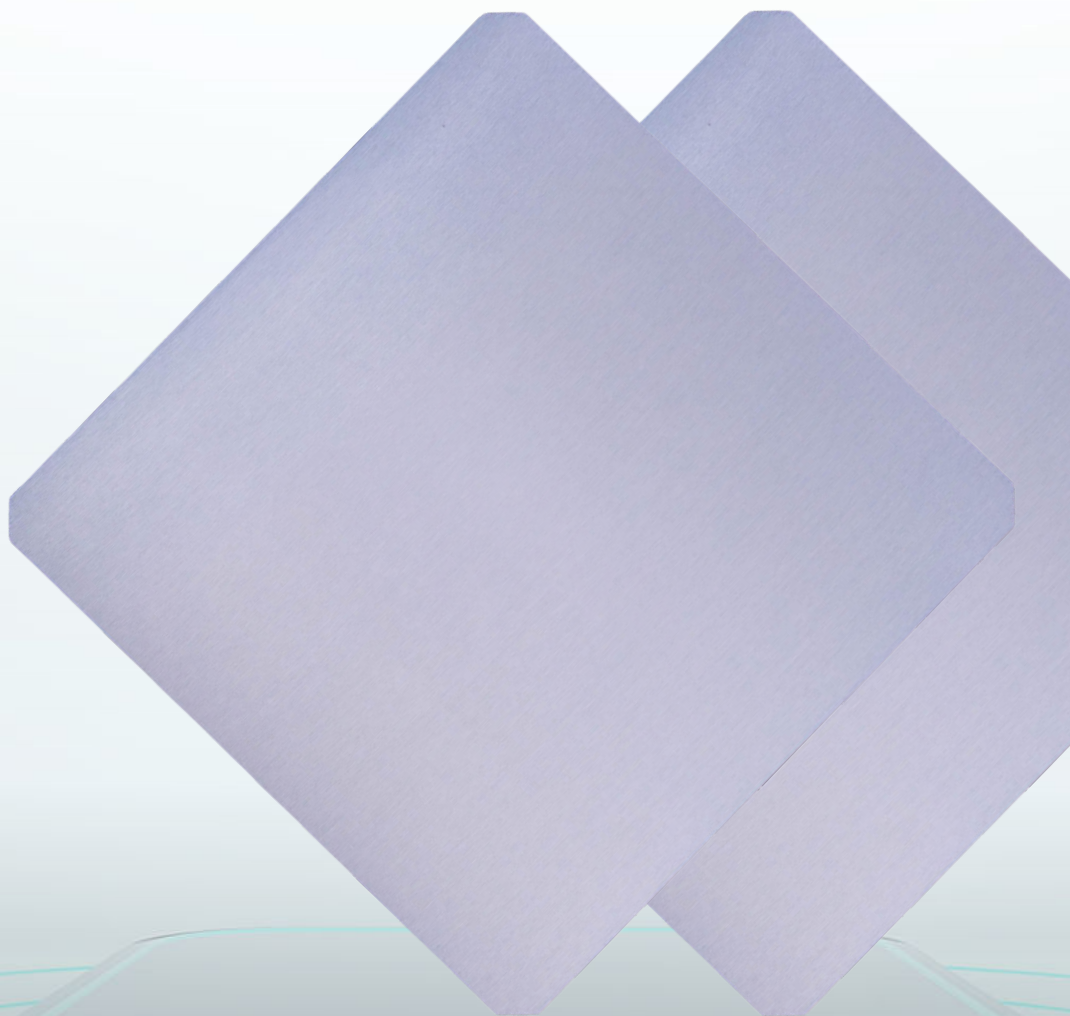
E: $183.75 \pm 0.25\text{mm}$

B: $\phi 247 \pm 0.25\text{mm}$

C1: $8.57 \pm 0.5\text{mm}$

C2: $8.49 \pm 0.5\text{mm}$

D: $90 \pm 0.15^\circ$



Monocrystalline Wafer Specification

N-type M10-C

Key parameters

Conductivity type	N-type	P/N type tester(DLY-2 P/N)
Dopant	Phos.	--
Resistivity/ $\Omega\cdot\text{cm}$	0.4-1.6	Wafer inspection system
MCLT(Minority carrier lifetime)/ μs	≥ 1000	Transient with injection level: $5\text{E}14\text{cm}^{-3}$ (Sinton BCT-400)
Oxygen concentration [Oi]/at/ cm^3	$\leq 6.0\times 10^{17}$	FTIR(ASTM F121-83)
Carbon Concentration [Cs]/at/ cm^3	$\leq 5.0\times 10^{16}$	FTIR(GB/T 1558-2009)

Material properties

Growth method	CZ	--
Crystallinity	Monocrystalline	--
Etch pit density (dislocation density)/pcs/ cm^2	≤ 500	Preferential Etch Techniques(ASTM F47-88)
Surface orientation/ $^\circ$	$\langle 100 \rangle \pm 3$	X-ray Diffraction Method (ASTM F26-1987)
Orientation of pseudo square sides/ $^\circ$	$\langle 010 \rangle, \langle 001 \rangle \pm 3$	X-ray Diffraction Method (ASTM F26-1987)

Geometric dimensions and surface properties

Wafer model	M10-C	--
Geometry	Pseudo square	--
Bevel edge shape	Round	--
Wafer Side length/mm	Short side 182.2 ± 0.25 ; Long side 183.75 ± 0.25	Wafer inspection system
Wafer Diameter/mm	$\phi 247\pm 0.25$	Wafer inspection system
Arc length projection/mm	C1: 8.57 ± 0.5 ; C2: 8.49 ± 0.5	Wafer inspection system
Angle between adjacent sides/ $^\circ$	90 ± 0.15	Wafer inspection system
Thickness/ μm	130 ± 8	Wafer inspection system
Batch mean/ μm	≥ 130	Wafer inspection system
Total thickness variation/ μm	≤ 20	Wafer inspection system
Saw marks/ μm	≤ 13	Wafer inspection system
Bow/ μm	≤ 40	Wafer inspection system
Warp/ μm	≤ 40	Wafer inspection system
Cutting method		--
Surface quality	as cut and cleaned, no visible contamination, color difference (as determined by standard sample) (oil or grease, finger prints, spot stains, epoxy/glue residue are not allowed)	Wafer inspection system
Chip	depth $\leq 0.3\text{mm}$ & length $\leq 0.5\text{mm}$,Max 1/pcs, no V-chip	Naked eyes or wafer inspection system
Micro cracks / holes	Not allowed	Wafer inspection system